

## **isc Silicon NPN Power Transistor**

# 2SD2125

#### **DESCRIPTION**

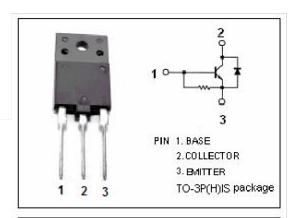
- · High Breakdown Voltage-
- : V<sub>CBO</sub>= 1500V (Min)
- · High Switching Speed
- Low Saturation Voltage
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

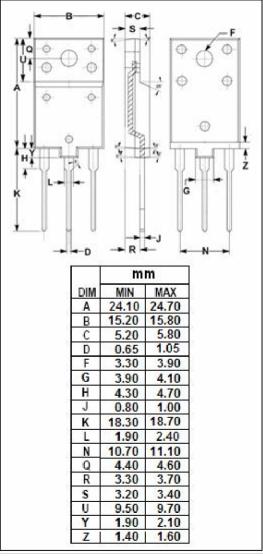


Designed for color TV horizontal output applications

ARSOLI	UTE MAXIMI	IM PATIN	GS(T=25°C)
		JIVI IX/A I II V	USI 18-45 C

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	600	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	6	Α
Ісм	Collector Current-Peak	10	Α
I <sub>B</sub>	Base Current- Continuous	3	А
Pc	Collector Power Dissipation @ T <sub>C</sub> =25°C	50	W
Тл	Junction Temperature	150	$^{\circ}$ C
T <sub>stg</sub> Storage Temperature Range		-55~150	$^{\circ}$ C







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 200mA; I <sub>C</sub> = 0	5			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 1A			5.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 1A			1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 500V; I <sub>E</sub> = 0			10	μ <b>А</b>
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	8		20	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 5A; V <sub>CE</sub> = 5V	5			
VECF	C-E Diode Forward Voltage	I <sub>F</sub> = 6A			2.0	V
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 10V		3		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> =1.0MHz		165		pF
t <sub>f</sub>	Fall Time	I <sub>CP</sub> = 5A, I <sub>B1(end)</sub> = 1A			0.5	μS

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